

RoHS

Phase Control Thyristors (Stud Version), 300 A



TO-118 (TO-209AE)

PRIMARY CHARACTERISTICS				
I _{T(AV)}	300 A			
V _{DRM} /V _{RRM}	400 V, 800 V, 1200 V, 1600 V, 1800 V, 2000 V			
V_{TM}	1.28 V			
I _{GT}	200 mA			
TJ	-40 °C to +125 °C			
Package	TO-118 (TO-209AE)			
Circuit configuration	Single SCR			

FEATURES

- Center amplifying gate
- International standard case TO-118 (TO-209AE)
- · Hermetic metal case with ceramic insulator



- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		300	A		
I _{T(AV)}	T _C	75	°C		
I _{T(RMS)}		470			
	50 Hz	8000	A		
I _{TSM}	60 Hz	8380			
I ² t	50 Hz	320	kA ² s		
1-1	60 Hz	292	- KA-S		
V _{DRM} /V _{RRM}		400 to 2000	V		
t _q	Typical	100	μs		
T _J		-40 to 125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM MA			
	04	400	500				
	08	800	900				
VS-ST300S	12	1200	1300	50			
V3-313003	16	1600	1700	50			
	18	1800	1900				
	20	2000	2100				



ABSOLUTE MAXIMUM RATINGS	S					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	L	180° condu	ction, half sine v	wave	300	Α
at case temperature	$I_{T(AV)}$				75	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 64 °C	case temperat	ure	470	
		t = 10 ms	No voltage		8000	
Maximum peak, one-cycle	L	t = 8.3 ms	reapplied		8380	A kA ² s
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal half wave, initial $T_J = T_J$ maximum	6730	
		t = 8.3 ms	reapplied		7040	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage		320	
		t = 8.3 ms	reapplied		292	
		t = 10 ms	100 % V _{RRM}		226	
		t = 8.3 ms	reapplied		207	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			3200	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$), $T_J = T_J$ maximum	0.97	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			v
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum		0.74	mΩ	
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.73	11152	
Maximum on-state voltage	V_{TM}	$I_{pk} = 940 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.66	V
Maximum holding current	I _H	T _ 05 °C	anada aupply 1	2 V registive lead	600	mΛ
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	- mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$	1.0	
Typical turn-off time	t _q	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs	100	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum linear to 80 % rated V _{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA



TRIGGERING						
PARAMETER	SYMBOL	TEST COMPLETIONS		VALUES		UNITS
PARAMETER	STWIBUL	16	ST CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	$t_p \leq 5 \; ms$	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	T. – T. maximum	t < 5 mg	20		V
Maximum peak negative gate voltage	- V _{GM}	ıj = ıj maximum,	$T_J = T_J$ maximum, $t_p \le 5$ ms		.0	
		T _J = -40 °C		200	-	
DC gate current required to trigger	I _{GT}	T _J = 25 °C	Manifestore was a size of a set a tributa of	100	200	mA
		T _J = 125 °C	Maximum required gate trigger/ current/voltage are the lowest	50	-	
		T _J = -40 °C	value which will trigger all units 12 V anode to cathode applied	2.5	-	
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 v anode to camode applied	1.8	3	٧
	T _J = 125 °C		1.1	-		
DC gate current not to trigger	I _{GD}	T T	Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	V_{GD}	$T_{\rm J} = T_{\rm J}$ maximum value which will not trigger any unit with rated $V_{\rm DRM}$ anode to cathode applied		0	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	TJ		-40 to 125	- °C	
Maximum storage temperature range	T _{Stg}		-40 to 150		
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.10	K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.03	7 ~~~	
Mounting torque, ± 10 %		Non-lubricated threads	48.5 (425)	N ⋅ m (lbf ⋅ in)	
Approximate weight			535	g	
Case style		See dimensions - link at the end of datasheet	TO-118 (TO-	-209AE)	

△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.011	0.008			
120°	0.013	0.014			
90°	0.017	0.018	$T_J = T_J$ maximum	K/W	
60°	0.025	0.026			
30°	0.041	0.042			

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

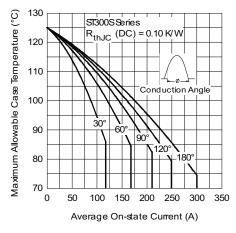


Fig. 1 - Current Ratings Characteristics

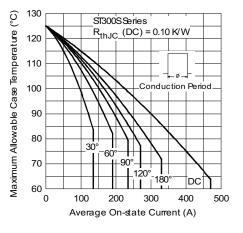


Fig. 2 - Current Ratings Characteristics

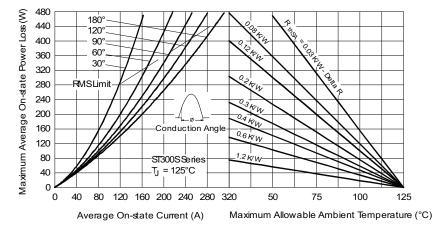


Fig. 3 - On-State Power Loss Characteristics

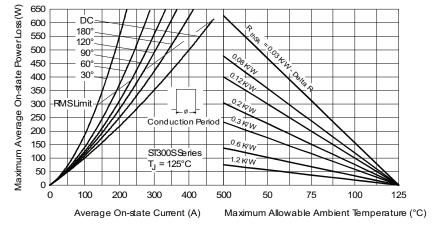


Fig. 4 - On-State Power Loss Characteristics

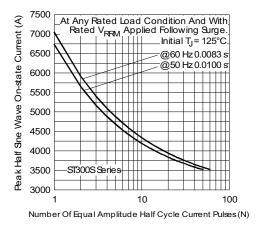


Fig. 5 - Maximum Non-Repetitive Surge Current

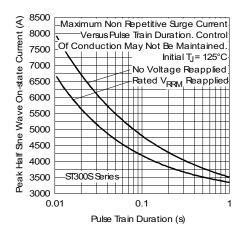


Fig. 6 - Maximum Non-Repetitive Surge Current

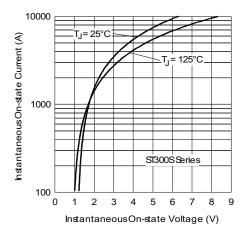


Fig. 7 - On-State Voltage Drop Characteristics

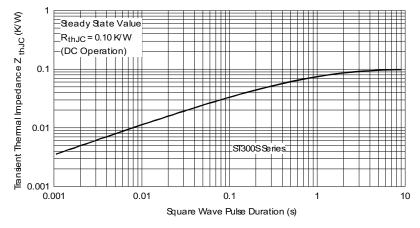


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

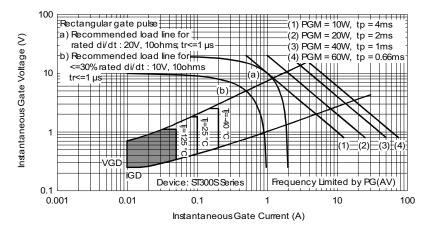
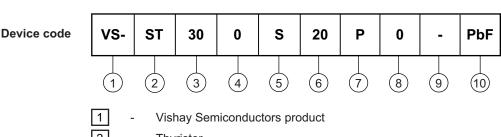


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE



2 - Thyristor

3 - Essential part number

4 - 0 = Converter grade

S = Compression bonding stud
 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - P = stud base 3/4" 16UNF-2A threads

M = stud base metric threads (M24 x 1.5)

8 - 0 = Eyelet terminals (gate and auxiliary cathode leads)

1 = Fast-on terminals (gate and auxiliary cathode leads)

3 = Threaded top terminal 3/8" 24UNF-2A

9 - Critical dV/dt: • None = 500 V/µs (standard value)

• L = 1000 V/μs (special selection)

10 - None = Standard production

- PbF = Lead (Pb)-free

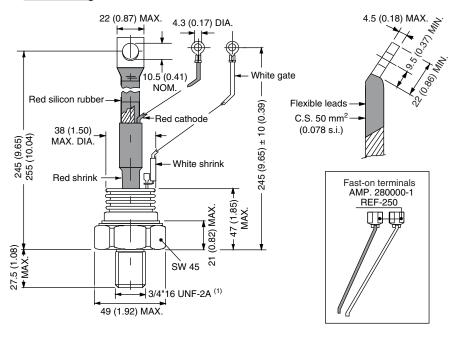
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95084	



TO-209AE (TO-118)

DIMENSIONS - TO-209AE (TO-118) in millimeters (inches)

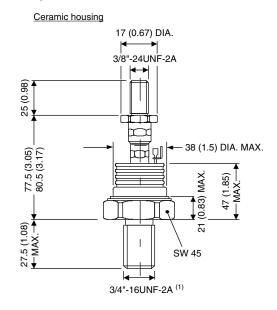
Ceramic housing



Note

 $^{(1)}$ For metric device: M24 x 1.5 - length screw 21 (0.83) maximum

DIMENSIONS - TO-209AE (TO-118) WITH TOP THREAD TERMINAL 3/8" in millimeters (inches)



Note

 $^{(1)}$ For metric device: M24 x 1.5 - length screw 21 (0.83) maximum

Document Number: 95084 Revision: 02-Aug-07



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.